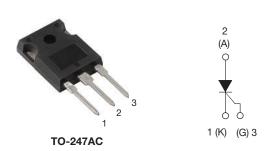
### VS-40TPS16PbF, VS-40TPS16-M3

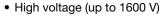
Vishay Semiconductors

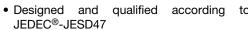
## Thyristor High Voltage, Phase Control SCR, 40 A



| PRODUCT SUMMARY                    |                  |  |  |  |  |  |  |  |
|------------------------------------|------------------|--|--|--|--|--|--|--|
| Package                            | TO-247AC         |  |  |  |  |  |  |  |
| Diode variation                    | Single SCR       |  |  |  |  |  |  |  |
| I <sub>T(AV)</sub>                 | 35 A             |  |  |  |  |  |  |  |
| V <sub>DRM</sub> /V <sub>RRM</sub> | 1600 V           |  |  |  |  |  |  |  |
| $V_{TM}$                           | 1.45 V           |  |  |  |  |  |  |  |
| I <sub>GT</sub>                    | 150 mA           |  |  |  |  |  |  |  |
| TJ                                 | -40 °C to 125 °C |  |  |  |  |  |  |  |

#### **FEATURES**







Material categorization:
For definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>







### **APPLICATIONS**

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

#### **DESCRIPTION**

The VS-40TPS16... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

| MAJOR RATINGS AND CHARACTERISTICS  |                              |            |       |  |  |  |  |  |  |
|------------------------------------|------------------------------|------------|-------|--|--|--|--|--|--|
| PARAMETER                          | TEST CONDITIONS              | VALUES     | UNITS |  |  |  |  |  |  |
| I <sub>T(AV)</sub>                 | Sinusoidal waveform          | 35         | А     |  |  |  |  |  |  |
| I <sub>RMS</sub>                   |                              | 55         |       |  |  |  |  |  |  |
| V <sub>RRM</sub> /V <sub>DRM</sub> |                              | 1600       | V     |  |  |  |  |  |  |
| I <sub>TSM</sub>                   |                              | 500        | А     |  |  |  |  |  |  |
| V <sub>T</sub>                     | 40 A, T <sub>J</sub> = 25 °C | 1.45       | V     |  |  |  |  |  |  |
| dV/dt                              |                              | 1000       | V/µs  |  |  |  |  |  |  |
| dl/dt                              |                              | 100        | A/µs  |  |  |  |  |  |  |
| T <sub>J</sub>                     |                              | -40 to 125 | °C    |  |  |  |  |  |  |

| VOLTAGE RATINGS              |   |   |   |  |  |  |  |  |  |  |
|------------------------------|---|---|---|--|--|--|--|--|--|--|
| PART NUMBER                  | V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM<br>REPETITIVE PEAK AND<br>OFF-STATE VOLTAGE<br>V | V <sub>RSM</sub> , MAXIMUM<br>NON-REPETITIVE PEAK<br>REVERSE VOLTAGE<br>V | I <sub>RRM</sub> /I <sub>DRM</sub><br>AT 125 °C<br>mA |  |  |  |  |  |  |  |
| VS-40TPS16PbF, VS-40TPS16-M3 | 1600  | 1700  | 10  |  |  |  |  |  |  |  |



# VS-40TPS16PbF, VS-40TPS16-M3

# Vishay Semiconductors

| ABSOLUTE MAXIMUM RATINGS                             |                                    |   |   |       |                    |  |  |  |
|--|------------------------------------|---|---|-------|--------------------|--|--|--|
| PARAMETER  | SYMBOL                             | TEST CONDITIONS   | VALUES  | UNITS |                    |  |  |  |
| Maximum average on-state current                     | I <sub>T(AV)</sub>                 | $T_C = 79 ^{\circ}\text{C}$ , $180^{\circ}$ conduction half sine wave | 35  |       |                    |  |  |  |
| Maximum continuous RMS on-state current as AC switch | I <sub>T(RMS)</sub>                |   |   | 55    | Α                  |  |  |  |
| Maximum peak, one-cycle                              | I <sub>TSM</sub>                   | 10 ms sine pulse, rated $V_{\text{RRM}}$ applied                      |   | 420   |                    |  |  |  |
| non-repetitive surge current                         | TISM                               | 10 ms sine pulse, no voltage reapplied                                |   | 500   |                    |  |  |  |
| Maximum I <sup>2</sup> t for fusing                  | l <sup>2</sup> t                   | 10 ms sine pulse, rated V <sub>RRM</sub> applied                      | Initial $T_J = T_H$ maximum                               | 880   | - A <sup>2</sup> s |  |  |  |
| Waxiiiluiii i-t for fusiiig                          | I-t                                | 10 ms sine pulse, no voltage reapplied                                | . 0   | 1250  |                    |  |  |  |
| Maximum I <sup>2</sup> √t for fusing                 | I <sup>2</sup> √t                  | t = 0.1 to 10 ms, no voltage reapplied                                | 12 500  | A²√s  |                    |  |  |  |
| Low level value of threshold voltage                 | V <sub>T(TO)1</sub>                |   |   | 1.02  | V                  |  |  |  |
| High level value of threshold voltage                | V <sub>T(TO)2</sub>                | T <sub>J</sub> = 125 °C   | 1.23  | V     |                    |  |  |  |
| Low level value of on-state slope resistance         | r <sub>t1</sub>                    | 1j = 125 C  |   | 9.74  | mΩ                 |  |  |  |
| High level value of on-state slope resistance        | r <sub>t2</sub>                    |   |   | 7.50  |                    |  |  |  |
| Maximum peak on-state voltage                        | $V_{TM}$                           | 110 A, T <sub>J</sub> = 25 °C   |   | 1.85  | V                  |  |  |  |
| Maximum rate of rise of turned-on current            | dl/dt                              | T <sub>J</sub> = 25 °C  |   | 100   | A/μs               |  |  |  |
| Maximum holding current                              | I <sub>H</sub>                     | Anode supply = 6 V, resistive load, initial $I_T$                     | 200   |       |                    |  |  |  |
| Maximum latching current                             | ΙL                                 | Anode supply = 6 V, resistive load, T <sub>J</sub> = 25               | 300   |       |                    |  |  |  |
| Marian na n         |                                    | T <sub>J</sub> = 25 °C  |   | 0.5   | mA                 |  |  |  |
| Maximum reverse and direct leakage current           | I <sub>RRM</sub> /I <sub>DRM</sub> | $T_J = 125  ^{\circ}\text{C}$ $V_R = \text{Rated } V_{RRM} / V_{DR}$  | V <sub>R</sub> = Rated V <sub>RRM</sub> /V <sub>DRM</sub> |       |                    |  |  |  |
| Maximum rate of rise of off-state voltage            | dV/dt                              | $T_J = T_J$ maximum, linear to 80 % $V_{DRM}$ , $R_g - k = Open$ 1000 |   |       |                    |  |  |  |

| TRIGGERING                                   |                    |   |                                   |      |         |
|--|--------------------|---|-----------------------------------|------|---------|
| PARAMETER                                    | SYMBOL             | 1   | TEST CONDITIONS                   |      |         |
| Maximum peak gate power                      | $P_{GM}$           |   |                                   |      |         |
| Maximum average gate power                   | P <sub>G(AV)</sub> |   |                                   | 2.5  | W       |
| Maximum peak gate current                    | I <sub>GM</sub>    |   |                                   | 2.5  | Α       |
| Maximum peak negative gate voltage           | - V <sub>GM</sub>  |   |                                   | 10   |         |
| Maximum required DC gate voltage to trigger  |                    | T <sub>J</sub> = - 40 °C                                |                                   | 4.0  | V<br>mA |
|  | $V_{GT}$           | T <sub>J</sub> = 25 °C                                  | Anode supply = 6 V resistive load | 2.5  |         |
| voltage to trigger                           |                    | T <sub>J</sub> = 125 °C                                 |                                   | 1.7  |         |
|  |                    | T <sub>J</sub> = - 40 °C                                |                                   | 270  |         |
| Maximum required DC gate augreent to trigger | l <sub>GT</sub>    | T <sub>J</sub> = 25 °C                                  | Anode supply = 6 V resistive load | 150  |         |
| Maximum required DC gate current to trigger  |                    | T <sub>J</sub> = 125 °C                                 |                                   | 80   |         |
|  |                    | T <sub>J</sub> = 25 °C, for 40                          | 40                                |      |         |
| Maximum DC gate voltage not to trigger       | $V_{GD}$           | T <sub>J</sub> = 125 °C, V <sub>DRM</sub> = Rated value |                                   | 0.25 | V       |
| Maximum DC gate current not to trigger       | $I_{GD}$           |   |                                   | 6    | mA      |



| THERMAL AND MECHANICAL SPECIFICATIONS           |         |                        |                                      |            |            |  |  |  |  |
|---|---------|------------------------|--------------------------------------|------------|------------|--|--|--|--|
| PARAMETER                                       |         | SYMBOL TEST CONDITIONS |                                      | VALUES     | UNITS      |  |  |  |  |
| Maximum junction and storage temperature range  |         | $T_J, T_Stg$           |                                      | -40 to 125 | °C         |  |  |  |  |
| Maximum thermal resistance, junction to case    |         | $R_{thJC}$             | DC operation                         | 0.6        |            |  |  |  |  |
| Maximum thermal resistance, junction to ambient |         | R <sub>thJA</sub>      |                                      | 40         | °C/W       |  |  |  |  |
| Maximum thermal resistance, case to heatsink    |         | R <sub>thCS</sub>      | Mounting surface, smooth and greased | 0.2        |            |  |  |  |  |
| Approximate weight                              |         |                        |                                      | 6          | g          |  |  |  |  |
| Approximate weight                              |         |                        |                                      | 0.21       | OZ.        |  |  |  |  |
| Mounting torque                                 | minimum |                        |                                      | 6 (5)      | kgf ⋅ cm   |  |  |  |  |
| Wounting torque                                 | maximum |                        |                                      | 12 (10)    | (lbf · in) |  |  |  |  |
| Marking device                                  |         |                        | Case style TO-247AC                  | 40TF       | PS16       |  |  |  |  |

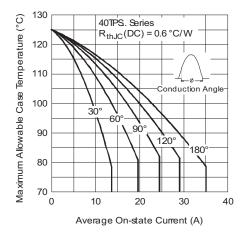


Fig. 1 - Current Rating Characteristics

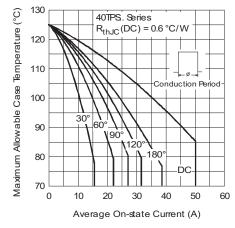


Fig. 2 - Current Rating Characteristics

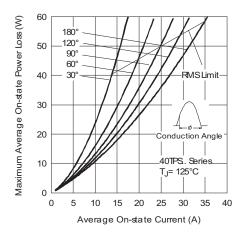


Fig. 3 - On-State Power Loss Characteristics

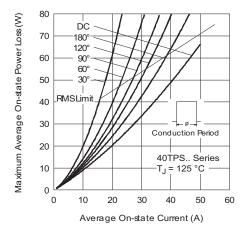


Fig. 4 - On-State Power Loss Characteristics

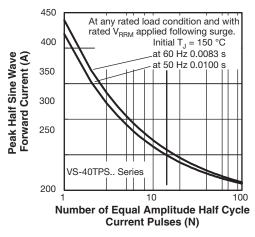


Fig. 5 - Maximum Non-Repetitive Surge Current

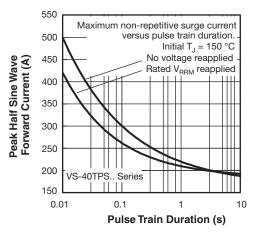


Fig. 6 - Maximum Non-Repetitive Surge Current

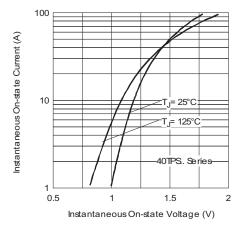


Fig. 7 - On-State Voltage Drop Characteristics

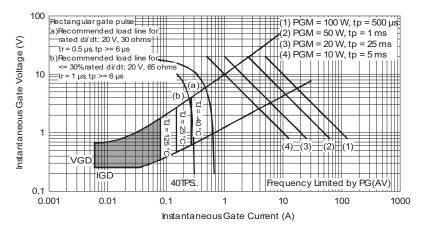


Fig. 8 - Gate Characteristics

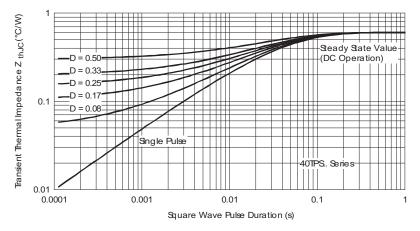
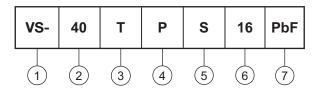


Fig. 9 - Thermal Impedance Z<sub>thJC</sub> Characteristics

#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (40 = 40 A)

- Circuit configuration:

T = Thyristor

Package:

P = TO-247

5 - Type of silicon:

S = Standard recovery rectifier

6 - Voltage rating (16 = 1600 V)

7 - Environmental digit:

PbF = Lead (Pb)-free and RoHS compliant

-M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

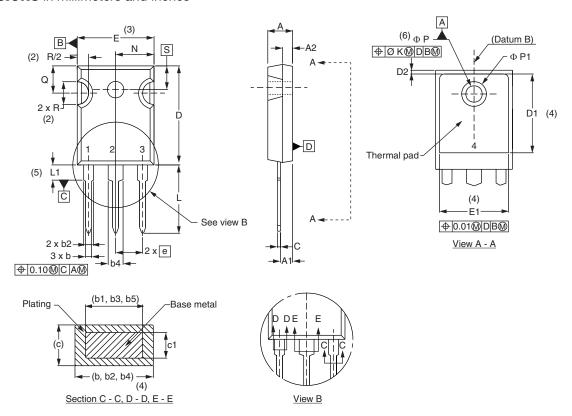
| ORDERING INFORMATION (Example) |                  |                        |                          |  |  |  |  |  |  |
|--------------------------------|------------------|------------------------|--------------------------|--|--|--|--|--|--|
| PREFERRED P/N                  | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION    |  |  |  |  |  |  |
| VS-40TPS16PbF                  | 25               | 500                    | Antistatic plastic tubes |  |  |  |  |  |  |
| VS-40TPS16-M3                  | 25               | 500                    | Antistatic plastic tubes |  |  |  |  |  |  |

| LINKS TO RELATED DOCUMENTS          |              |                          |  |  |  |  |
|-------------------------------------|--------------|--------------------------|--|--|--|--|
| Dimensions www.vishay.com/doc?95542 |              |                          |  |  |  |  |
| Part marking information            | TO-247AC PbF | www.vishay.com/doc?95226 |  |  |  |  |
|                                     | TO-247AC -M3 | www.vishay.com/doc?95007 |  |  |  |  |



### TO-247 - 50 mils L/F

#### **DIMENSIONS** in millimeters and inches



| SYMBOL | MILLIN | MILLIMETERS |       | INCHES |       | NOTES | SYMBOL  | MILLIMETERS |       | INCHES |       | NOTES |
|--------|--------|-------------|-------|--------|-------|-------|---------|-------------|-------|--------|-------|-------|
| STMBOL | MIN.   | MAX.        | MIN.  | MAX.   | NOTES |       | STWIBOL | MIN.        | MAX.  | MIN.   | MAX.  | NOTES |
| Α      | 4.65   | 5.31        | 0.183 | 0.209  |       |       | D2      | 0.51        | 1.35  | 0.020  | 0.053 |       |
| A1     | 2.21   | 2.59        | 0.087 | 0.102  |       |       | E       | 15.29       | 15.87 | 0.602  | 0.625 | 3     |
| A2     | 1.17   | 1.37        | 0.046 | 0.054  |       |       | E1      | 13.46       | -     | 0.53   | -     |       |
| b      | 0.99   | 1.40        | 0.039 | 0.055  |       |       | е       | 5.46        | BSC   | 0.215  | BSC   |       |
| b1     | 0.99   | 1.35        | 0.039 | 0.053  |       |       | ØΚ      | 0.2         | 254   | 0.0    | )10   |       |
| b2     | 1.65   | 2.39        | 0.065 | 0.094  |       |       | L       | 14.20       | 16.10 | 0.559  | 0.634 |       |
| b3     | 1.65   | 2.34        | 0.065 | 0.092  |       |       | L1      | 3.71        | 4.29  | 0.146  | 0.169 |       |
| b4     | 2.59   | 3.43        | 0.102 | 0.135  |       |       | Ν       | 7.62        | BSC   | 0      | .3    |       |
| b5     | 2.59   | 3.38        | 0.102 | 0.133  |       |       | ØΡ      | 3.56        | 3.66  | 0.14   | 0.144 |       |
| С      | 0.38   | 0.89        | 0.015 | 0.035  |       |       | Ø P1    | -           | 7.39  | -      | 0.291 |       |
| c1     | 0.38   | 0.84        | 0.015 | 0.033  |       |       | Q       | 5.31        | 5.69  | 0.209  | 0.224 |       |
| D      | 19.71  | 20.70       | 0.776 | 0.815  | 3     |       | R       | 4.52        | 5.49  | 0.178  | 0.216 |       |
| D1     | 13.08  | -           | 0.515 | -      | 4     |       | S       | 5.51        | BSC   | 0.217  | 'BSC  |       |

#### **Notes**

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- $^{(7)}$  Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



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Vishay

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